Hardware Change Log

*[P80 PMU]*

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| Document Reference: |  | | |
| Document Revision: |  | Date: | *08-03-2018* |
| **Comments** | | | |
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| Action | Name | Function | Signature | Date |
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| Prepared: | JOKR |  |  | 08-03-2018 |
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| Approved by: |  |  |  |  |

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# Changelog

|  |  |  |  |
| --- | --- | --- | --- |
| Date | Revision | Author | Description |
|  |  |  |  |
| 12-12-2017 | 1 |  | Initial release first prototype - EDA build no. 17.1.9.592 |

# Purpose and Scope

This document describes the changes for each revision of the P80 PMU.

Raw PCB Number: 100608

# Changes to be implemented (Pending)

|  |  |  |  |  |  |  |
| --- | --- | --- | --- | --- | --- | --- |
| No. | Description | BOM | Schematic | Layout | Who | Status |
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|  |  |  |  |  |  |  |
| 4 | GAN FET to be changed to MOSFET, or GAN Systems FET with much lower gate-source leakage. |  | X | X | BGS |  |
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|  |  |  |  |  |  |  |
| ~~9~~ | ~~Change R176, R177, R187 and R188 to 100k and C152 and C165 to reduce deploy peak current from 1.8A to 18mA without load. This to ensure overcurrent is not tripped from inrush current.~~ | ~~X~~ |  |  | ~~CAF~~ |  |
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|  |  |  |  |  |  |  |
| 13 | How is charge initially applied to C106 and C107 is a diode from VCC to VBAT missing? Is capacitance sufficient with self-discharge? | X | X | X | CAF |  |
| 14 | Is the added resolution on U3 necessary? VM\_VBAT and CM\_VBAT are both routed to U1 and U2 respectively and hence measured twice. | X | X | X | CAF |  |
|  |  |  |  |  |  |  |
| 16 | Datasheet for ADS7952 (U1 & U2) states requirement for a 10µF capacitor between REF and GND as close as possible to the IC.  Additionally the datasheet recommends 1µF at each supply pin placed as close as possible to the IC. | X | X | X | CAF |  |
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| 20 | Vref (VM5) on ADC is irrelevant. |  |  |  |  |  |
| 21 | Update Killswitch circuitry to reflect P80\_killswitch\_overview v3 | X | X | X | CAF |  |
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# Revision 2 changes implemented

|  |  |  |  |  |  |  |
| --- | --- | --- | --- | --- | --- | --- |
| No. | Description | BOM | Schematic | Layout | Who | Status |
| 1 | U26 SYNC Oscillator, Pin 2 GND is connected to VCC through R142, 100kohm, Pin 3 SET is connected to GND. |  | X | X | JOKR | Done |
| 5 | Add zero ohms for RS485 connection to main bus |  | X | X | BGS | Done |
| 23 | Change net ties in main connector to 10R resistors |  | X | X | BGS | Done |
| 7 | If new MCU: add write protect capability to FRAM |  | X | X | BGS | Done |
| 8 | If new MCU: add CAN mode control |  | X | X | BGS | Done |
| 24 | Change MCU to 100 pin version | X | X | X | BGS | Done |
| 25 | Change load switches, note P60 issues  Missing component calculations | X | X | X | BGS | Done |
| 22 | Reverse GSRB connections |  | X | X | BGS | Done |
| 6 | GPIOs PB00 and PB01 are used twice: |  | X | X | BGS | Done |
| 2 | Q4 MOSFET Vgs voltage can get higher than absolute maximum rating off -20V vhen Vbat gets higher than 30V  Not relevant anymore | X | X |  | JOKR | Done |
| 3 | Low voltage loadswitches needs to be changed. |  | X | X | BGS | Done |
| 10 | R175 and R186 is not required due to DFF logic. DFF logic can be replaced with a 5V CMOS level shifter, hence R175 and R186 will prevent retry functionality as per Figure 4 in LT1910 datasheet  Not relevant anymore | X | X | X | CAF | Done |
| 15 | R26 should be 10k. | X |  |  | CAF | Done |
| 17 | Add series termination to SPI bus to reduce ringing. Possibly footprint for a load capacitor as well. | X | X | X | CAF | Done |
| 18 | R115 should be located as close as possible to the MCU to work as series termination. Ringing from RX/TX are causing crosstalk.  R115 and R118 should be changed to 100ohm. Could be more, but trimming should occur on next revision.    10 ohm series resistor    100 ohm series resistor    The result after changing to 100 ohm | X |  | X | CAF | Done |
| 19 | R131 + R134 can cause VGS max to exceede limits of +/- 20V  Not relevant anymore |  |  |  |  | Done |
| 11 | Change R130 to 1k  nReset on MCU sees a small pulse high on power on.  Ch1: Yellow VCC @ U23 pin 5  Ch2: Cyan nRESET @ U23 pin 1  Ch3: Magenta WDI @ U23 pin 4  Ch4: Blue nRESET @ U18 pin 64  On power up, RESET\_N on MCU is pulled towards VCC which is causing the glitch. Could this be an issue for an open collector?  R130 = 1k  This cannot be prevented by supervisor circuitry as it is the MCU who generate it.  Resistor changed, Open-Collector WD version is considered |  |  |  | CAF | Done |
| 12 | Supervisor circuitry generated reset (U23) could be replaced or OR’ed with PG from load switch (U42).  Not implemented |  | X | X | CAF | Done |
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